
	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 1 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Annex A: Measurement data and plots

A.1 MIF validation plots

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 2 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 12:00:00 AM

Test Laboratory: BlackBerry RTS

MIF_measurements_03_18-24_14

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ; Calibrated: 1/17/2014
- Sensor-Surface: 0mm (Fix Surface), z = 2.5
- Electronics: DAE3 Sn473; Calibrated: 1/15/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.6(1115); SEMCAD X 14.6.9(7117)

Configuration/MIF Measurements/MIF_AM80%_1KHz_Measurement

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-1.29 dB		0.00 dB	Power High
PMF	3.81 dB	1.551	0.00 dB	Power High
Detector Level	10.61 dBm		0.00 dB	Power High
RFAIP	9.32 dBm		0.00 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_AM10%_1KHz_Measurement

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-9.22 dB		0.00 dB	Power OK
PMF	0.78 dB	1.094	0.00 dB	Power OK
Detector Level	10.46 dBm		0.00 dB	Power OK
RFAIP	1.24 dBm		0.00 dB	(MIF+CF+Detector Level)



Author Data
Daoud Attayi

Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW

Configuration/MIF Measurements/MIF_AM1%_1KHz_Measurement

Calibration Factors: 1.090, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-19.18 dB		0.00 dB	Power OK
PMF	0.08 dB	1.010	0.00 dB	Power OK
Detector Level	10.43 dBm		0.00 dB	Power OK
RFAIP	-8.75 dBm		0.00 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_GSM_Measurement

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	3.44 dB		0.00 dB	Power OK
PMF	9.86 dB	3.112	0.01 dB	Power OK
Detector Level	-0.64 dBm		0.00 dB	Power OK
RFAIP	2.80 dBm		0.01 dB	(MIF+CF+Detector Level)

Configuration/MIF

Measurements/MIF_WCDMA_Voice_AMR12_2kps_Measurement

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-25.91 dB		0.18 dB	Power OK
PMF	0.06 dB	1.007	0.00 dB	Power OK
Detector Level	0.11 dBm		0.02 dB	Power OK
RFAIP	-25.80 dBm		0.19 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11b_Rate_1Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
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Document

Annex A to Hearing Aid Compatibility RF Emissions Test
Report for the BlackBerry® Smartphone model RHA111LW

Page

4 (46)

Author Data

Daoud Attayi

Dates of Test

March 18-24, July 14-15, 2014

Report No

RTS-6058-1407-06

FCC ID

L6ARHA110LW

MIF	-12.65 dB		0.02 dB	Power OK
PMF	0.40 dB	1.047	0.03 dB	Power OK
Detector Level	4.02 dBm		0.02 dB	Power OK
RFAIP	-8.63 dBm		0.04 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11b_Rate_2Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-11.97 dB		0.01 dB	Power OK
PMF	0.45 dB	1.053	0.01 dB	Power OK
Detector Level	4.06 dBm		0.01 dB	Power OK
RFAIP	-7.91 dBm		0.02 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11b_Rate_5.5Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-9.49 dB		0.00 dB	Power OK
PMF	0.65 dB	1.078	0.02 dB	Power OK
Detector Level	4.08 dBm		0.00 dB	Power OK
RFAIP	-5.41 dBm		0.01 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11b_Rate_11Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-8.71 dB		0.04 dB	Power OK
PMF	0.78 dB	1.094	0.04 dB	Power OK
Detector Level	3.89 dBm		0.05 dB	Power OK
RFAIP	-4.82 dBm		0.09 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11g_Rate_6Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
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Document

Annex A to Hearing Aid Compatibility RF Emissions Test
Report for the BlackBerry® Smartphone model RHA111LW

Page

5 (46)

Author Data

Daoud Attayi

Dates of Test

March 18-24, July 14-15, 2014

Report No

RTS-6058-1407-06

FCC ID

L6ARHA110LW

MIF	-10.27 dB		0.01 dB	Power OK
PMF	0.81 dB	1.098	0.02 dB	Power OK
Detector Level	4.47 dBm		0.00 dB	Power OK
RFAIP	-5.80 dBm		0.02 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11g_Rate_9Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-9.52 dB		0.02 dB	Power OK
PMF	0.90 dB	1.109	0.02 dB	Power OK
Detector Level	4.40 dBm		0.01 dB	Power OK
RFAIP	-5.12 dBm		0.03 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11g_Rate_18Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-8.31 dB		0.01 dB	Power OK
PMF	1.08 dB	1.133	0.05 dB	Power OK
Detector Level	4.16 dBm		0.01 dB	Power OK
RFAIP	-4.15 dBm		0.02 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11g_Rate_54Mbps

Calibration Factors: 1.089, 1.088; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-8.68 dB		0.01 dB	Power OK
PMF	1.91 dB	1.246	0.04 dB	Power OK
Detector Level	3.46 dBm		0.01 dB	Power OK
RFAIP	-5.22 dBm		0.01 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11a_Rate_6Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
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Document

**Annex A to Hearing Aid Compatibility RF Emissions Test
Report for the BlackBerry® Smartphone model RHA111LW**

Page

6 (46)

Author Data

Daoud Attayi

Dates of Test

March 18-24, July 14-15, 2014

Report No

RTS-6058-1407-06

FCC ID

L6ARHA110LW

MIF	-10.40 dB		0.04 dB	Power OK
PMF	0.82 dB	1.100	0.03 dB	Power OK
Detector Level	0.13 dBm		0.02 dB	Power OK
RFAIP	-10.27 dBm		0.05 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11a_Rate_24Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.43 dB		0.02 dB	Power OK
PMF	0.81 dB	1.098	0.03 dB	Power OK
Detector Level	0.11 dBm		0.01 dB	Power OK
RFAIP	-10.32 dBm		0.03 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11a_Rate_54Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.43 dB		0.02 dB	Power OK
PMF	0.81 dB	1.098	0.03 dB	Power OK
Detector Level	0.09 dBm		0.01 dB	Power OK
RFAIP	-10.34 dBm		0.02 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11n_Rate_6.5Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.40 dB		0.03 dB	Power OK
PMF	0.83 dB	1.100	0.03 dB	Power OK
Detector Level	0.13 dBm		0.03 dB	Power OK
RFAIP	-10.27 dBm		0.06 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11n_Rate_39Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
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Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06	FCC ID L6ARHA110LW
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MIF	-10.43 dB		0.02 dB	Power OK
PMF	0.82 dB	1.099	0.02 dB	Power OK
Detector Level	0.17 dBm		0.01 dB	Power OK
RFAIP	-10.26 dBm		0.03 dB	(MIF+CF+Detector Level)

Configuration/MIF Measurements/MIF_802.11n_Rate_65Mbps

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.43 dB		0.01 dB	Power OK
PMF	0.81 dB	1.098	0.02 dB	Power OK
Detector Level	0.16 dBm		0.00 dB	Power OK
RFAIP	-10.27 dBm		0.02 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

QPSK_Measurements/MIF_LTE_20MHz_BW_QPSK_RB1_Offset0_Measurement

Calibration Factors: 1.089, 1.088; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-14.58 dB		0.07 dB	Power OK
PMF	1.82 dB	1.234	0.36 dB	Power OK
Detector Level	5.25 dBm		0.09 dB	Power OK
RFAIP	-9.34 dBm		0.16 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

QPSK_Measurements/MIF_LTE_20MHz_BW_QPSK_RB1_Offset50_Measurement

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-14.57 dB		0.07 dB	Power OK
PMF	1.84 dB	1.237	0.41 dB	Power OK
Detector Level	4.96 dBm		0.07 dB	Power OK
RFAIP	-9.60 dBm		0.14 dB	(MIF+CF+Detector Level)

**Configuration/MIF_LTE
QPSK_Measurements/MIF_LTE_20MHz_BW_QPSK_RB1_Offset99_Measurement**

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-14.47 dB		0.07 dB	Power OK
PMF	1.72 dB	1.219	0.38 dB	Power OK
Detector Level	4.60 dBm		0.04 dB	Power OK
RFAIP	-9.87 dBm		0.11 dB	(MIF+CF+Detector Level)

**Configuration/MIF_LTE
QPSK_Measurements/MIF_LTE_20MHz_BW_QPSK_RB50_Offset0_Measurement**

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-21.01 dB		0.22 dB	Power OK
PMF	0.16 dB	1.019	0.02 dB	Power OK
Detector Level	3.93 dBm		0.10 dB	Power OK
RFAIP	-17.08 dBm		0.32 dB	(MIF+CF+Detector Level)

**Configuration/MIF_LTE
QPSK_Measurements/MIF_LTE_20MHz_BW_QPSK_RB100_Offset0_Measurement**

Calibration Factors: 1.089, 1.088; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-21.97 dB		0.33 dB	Power OK
PMF	0.15 dB	1.017	0.02 dB	Power OK
Detector Level	3.89 dBm		0.08 dB	Power OK
RFAIP	-18.08 dBm		0.41 dB	(MIF+CF+Detector Level)

**Configuration/MIF_LTE
QPSK_Measurements/MIF_LTE_15MHz_BW_QPSK_RB1_Offset0_Measurement**

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Calibration Factors: 1.090, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-14.75 dB		0.04 dB	Power OK
PMF	1.68 dB	1.213	0.24 dB	Power OK
Detector Level	5.14 dBm		0.07 dB	Power OK
RFAIP	-9.61 dBm		0.11 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

QPSK_Measurements/MIF_LTE_10MHz_BW_QPSK_RB1_Offset0_Measurement

Calibration Factors: 1.090, 1.090; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-14.93 dB		0.03 dB	Power OK
PMF	1.51 dB	1.190	0.15 dB	Power OK
Detector Level	4.98 dBm		0.06 dB	Power OK
RFAIP	-9.95 dBm		0.09 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

QPSK_Measurements/MIF_LTE_5MHz_BW_QPSK_RB1_Offset0_Measurement

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-14.74 dB		0.00 dB	Power OK
PMF	1.57 dB	1.198	0.08 dB	Power OK
Detector Level	4.93 dBm		0.00 dB	Power OK
RFAIP	-9.81 dBm		0.01 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

QPSK_Measurements/MIF_LTE_3MHz_BW_QPSK_RB1_Offset0_Measurement

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB



Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06	FCC ID L6ARHA110LW
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Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-14.70 dB		0.05 dB	Power OK
PMF	1.55 dB	1.196	0.25 dB	Power OK
Detector Level	4.98 dBm		0.08 dB	Power OK
RFAIP	-9.71 dBm		0.14 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

QPSK_Measurements/MIF_LTE_1.4MHz_BW_QPSK_RB1_Offset0_Measurement

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-14.84 dB		0.04 dB	Power OK
PMF	1.39 dB	1.174	0.11 dB	Power OK
Detector Level	5.11 dBm		0.06 dB	Power OK
RFAIP	-9.74 dBm		0.10 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

16QAM_Measurements/MIF_LTE_20MHz_BW_16QAM_RB1_Offset0_Measurement

Calibration Factors: 1.089, 1.088; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.58 dB		0.02 dB	Power OK
PMF	2.48 dB	1.331	0.15 dB	Power OK
Detector Level	4.20 dBm		0.04 dB	Power OK
RFAIP	-6.38 dBm		0.06 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

16QAM_Measurements/MIF_LTE_20MHz_BW_16QAM_RB1_Offset50_Measurement

Calibration Factors: 1.089, 1.088; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.56 dB		0.05 dB	Power OK



Document

**Annex A to Hearing Aid Compatibility RF Emissions Test
Report for the BlackBerry® Smartphone model RHA111LW**

Page

11 (46)

Author Data

Daoud Attayi

Dates of Test

March 18-24, July 14-15, 2014

Report No

RTS-6058-1407-06

FCC ID

L6ARHA110LW

PMF	2.50 dB	1.333	0.12 dB	Power OK
Detector Level	4.03 dBm		0.08 dB	Power OK
RFAIP	-6.53 dBm		0.13 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE**16QAM_Measurements/MIF_LTE_20MHz_BW_16QAM_RB1_Offset99_Meas
urement**

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.55 dB		0.04 dB	Power OK
PMF	2.50 dB	1.333	0.12 dB	Power OK
Detector Level	3.65 dBm		0.05 dB	Power OK
RFAIP	-6.90 dBm		0.09 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE**16QAM_Measurements/MIF_LTE_20MHz_BW_16QAM_RB24_Offset0_Meas
urement**

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-16.41 dB		0.05 dB	Power OK
PMF	0.58 dB	1.069	0.07 dB	Power OK
Detector Level	3.07 dBm		0.10 dB	Power OK
RFAIP	-13.33 dBm		0.15 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE**16QAM_Measurements/MIF_LTE_20MHz_BW_16QAM_RB100_Offset0_Meas
urement**

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-17.67 dB		0.07 dB	Power OK
PMF	0.34 dB	1.040	0.03 dB	Power OK
Detector Level	2.81 dBm		0.10 dB	Power OK
RFAIP	-14.86 dBm		0.16 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

**16QAM_Measurements/MIF_LTE_15MHz_BW_16QAM_RB1_Offset0_Measur
ement**

Calibration Factors: 1.090, 1.090; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.07 dB		0.05 dB	Power OK
PMF	2.36 dB	1.313	0.21 dB	Power OK
Detector Level	4.25 dBm		0.06 dB	Power OK
RFAIP	-5.82 dBm		0.11 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

**16QAM_Measurements/MIF_LTE_10MHz_BW_16QAM_RB1_Offset0_Measur
ement**

Calibration Factors: 1.090, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.03 dB		0.04 dB	Power OK
PMF	2.37 dB	1.313	0.17 dB	Power OK
Detector Level	4.19 dBm		0.08 dB	Power OK
RFAIP	-5.85 dBm		0.12 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

**16QAM_Measurements/MIF_LTE_5MHz_BW_16QAM_RB1_Offset0_Measure
ment**

Calibration Factors: 1.090, 1.090; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.98 dB		0.04 dB	Power OK
PMF	2.62 dB	1.353	0.32 dB	Power OK
Detector Level	3.78 dBm		0.08 dB	Power OK
RFAIP	-7.20 dBm		0.13 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE

16QAM_Measurements/MIF_LTE_3MHz_BW_16QAM_RB1_Offset0_Measure



Author Data
Daoud Attayi

Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW

ment

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB


Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.15 dB		0.03 dB	Power OK
PMF	2.35 dB	1.311	0.20 dB	Power OK
Detector Level	4.19 dBm		0.07 dB	Power OK
RFAIP	-5.96 dBm		0.10 dB	(MIF+CF+Detector Level)

Configuration/MIF_LTE


16QAM_Measurements/MIF_LTE_1.4MHz_BW_16QAM_RB1_Offset0_Measurment

Calibration Factors: 1.089, 1.089; MIF Scale: 0.00 dB; Coupling Factor (CF): 0.00 dB

Quantity	Value [log]	[linear]	Fluctuation	Remark
MIF	-10.41 dB		0.05 dB	Power OK
PMF	2.97 dB	1.407	0.30 dB	Power OK
Detector Level	3.98 dBm		0.08 dB	Power OK
RFAIP	-6.43 dBm		0.14 dB	(MIF+CF+Detector Level)

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 14 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

A.2 Dipole validation

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 15 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 7/15/2014 9:51:37 AM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_validation_07_15_14

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1089

Communication System: UID 0, CW For MIF; Frequency: 835 MHz
Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³
Phantom section: RF Section
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 9.7
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

CD835 Dipole E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - measurement distance from the probe sensor center to CD835 = 15mm/Hearing Aid Compatibility Test at 15mm distance (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 104.3 V/m; Power Drift = 0.02 dB
PMR not calibrated. PMF = 1.000 is applied.
E-field emissions = 110.4 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 M4 99.47 V/m	Grid 2 M4 103.8 V/m	Grid 3 M4 103.8 V/m
Grid 4 M4 58.97 V/m	Grid 5 M4 60.73 V/m	Grid 6 M4 60.55 V/m



Author Data
Daoud Attayi

Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW

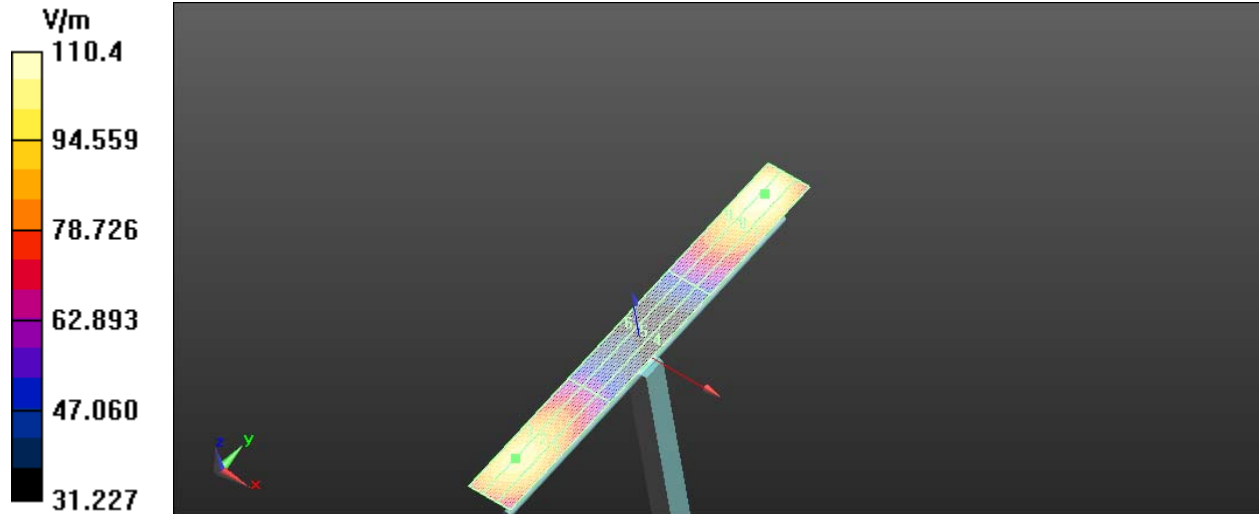
Grid 7 M4 104.9 V/m	Grid 8 M4 110.4 V/m	Grid 9 M4 110.1 V/m
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Cursor:

Total = 110.4 V/m

E Category: M4

Location: -2, 78, 9.7 mm



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 17 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 7/15/2014 10:18:37 AM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_validation_07_15_14

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1068

Communication System: UID 0, CW For MIF; Frequency: 1880 MHz

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 9.7
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

CD1880 Dipole E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - measurement distance from the probe sensor center to CD1880 = 15mm/Hearing Aid Compatibility Test at 15mm distance (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 147.5 V/m; Power Drift = -0.05 dB

PMR not calibrated. PMF = 1.000 is applied.

E-field emissions = 85.14 V/m

Near-field category: M3 (AWF 0 dB)

PMF scaled E-field

Grid 1 M3 80.00 V/m	Grid 2 M3 82.16 V/m	Grid 3 M3 81.30 V/m
Grid 4 M3 65.54 V/m	Grid 5 M3 66.50 V/m	Grid 6 M3 65.53 V/m



Author Data
Daoud Attayi

Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW

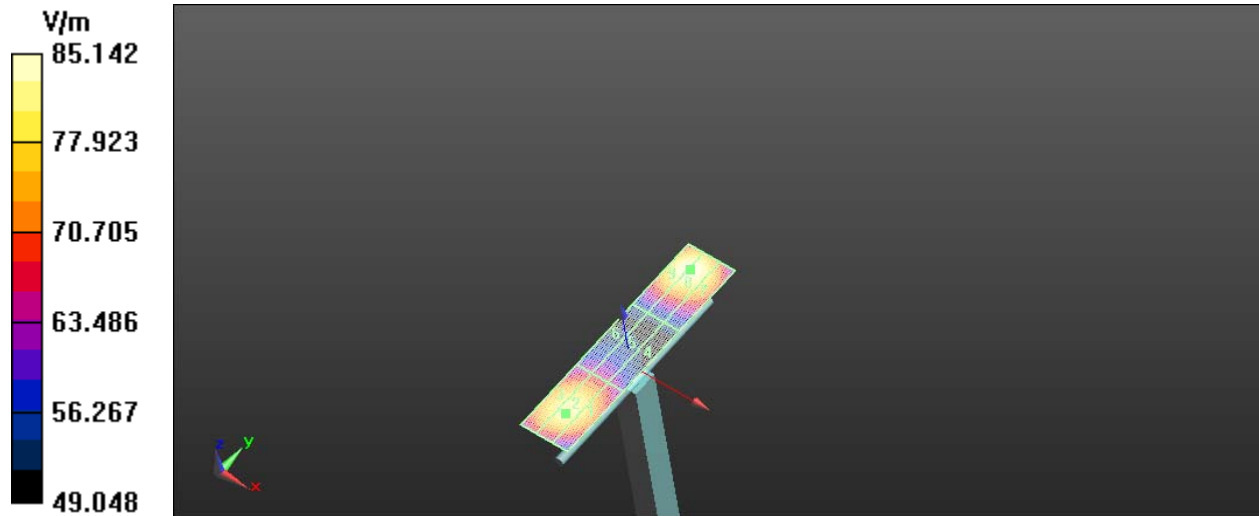
Grid 7 M3 80.34 V/m	Grid 8 M3 85.14 V/m	Grid 9 M3 85.09 V/m
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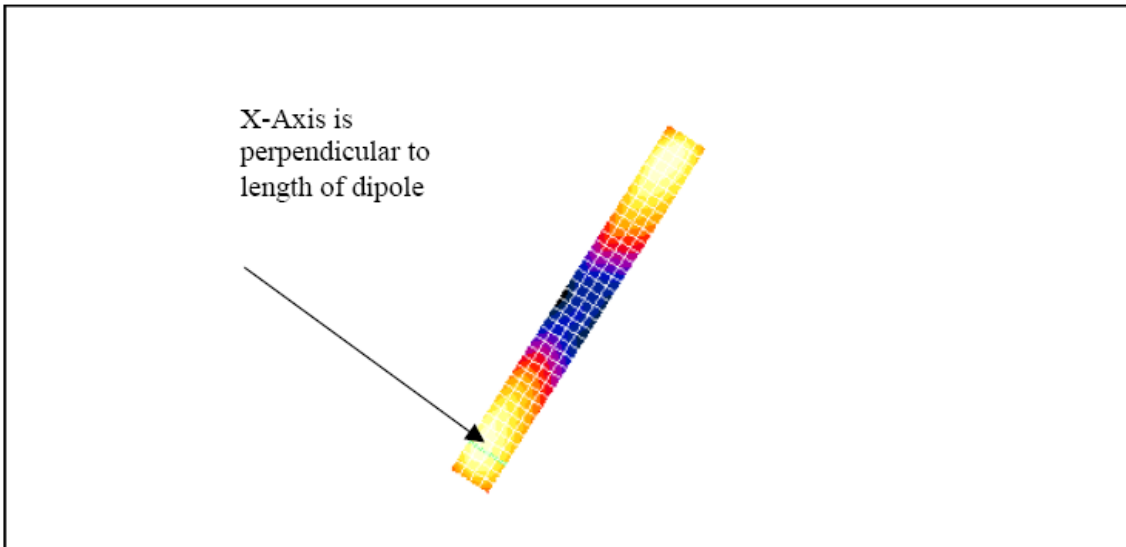
Cursor:

Total = 85.14 V/m

E Category: M3

Location: -3, 37, 9.7 mm





The green line in this figure shows the axis along which the points lie.

Comparison of 5mm and 2mm step sizes

An additional set of measurements was taken: dipole validations were performed using 5mm and 2mm step sizes. The delta between the two readings is insignificant for both field types ($< 0.4\%$ for E and 0% for H), demonstrating that 5mm is sufficient. The plots follow.



Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06	FCC ID L6ARHA110LW
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Date/Time: 14/07/2005 11:35:24 AM

Page 1 of 2

Date/Time: 14/07/2005 11:35:24 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1
 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
 Phantom section: H Device Section

DASY4 Configuration:
 - Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004
 - Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
 - Electronics: DAE3 Sn472; Calibrated: 03/01/2005
 - Phantom: HAC Test Arch; Type: SD HAC P01 BA;
 - Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of Total (measured) = 134.8 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm
 Maximum value of Total field (slot averaged) = 131.0 V/m

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

E in V/m (Time averaged)			E in V/m (Slot averaged)		
Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
123.2	138.1	138.4	123.2	138.1	138.4
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
80.9	92.3	92.2	80.9	92.3	92.2
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
119.8	131.0	130.7	119.8	131.0	130.7

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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Author Data
Daoud Attayi

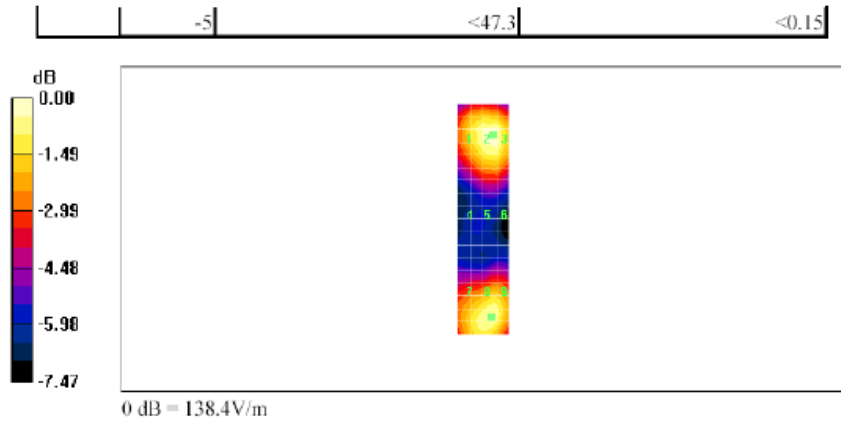
Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW

Date/Time: 14/07/2005 11:35:24 AM

Page 2 of 2



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Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06	FCC ID L6ARHA110LW
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Date/Time: 14/07/2005 11:44:51 AM

Page 1 of 2

Date/Time: 14/07/2005 11:44:51 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_2mm step_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1
 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³
 Phantom section: H Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1):

Measurement grid: dx=2mm, dy=2mm
 Maximum value of Total (measured) = 138.0 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):

Measurement grid: dx=2mm, dy=2mm
 Maximum value of Total field (slot averaged) = 131.2 V/m

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

E in V/m (Time averaged) E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
123.1	138.6	138.6	123.1	138.6	138.6
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
81.4	92.1	91.6	81.4	92.1	91.6
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
121.3	131.2	131.0	121.3	131.2	131.0

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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Author Data
Daoud Attayi

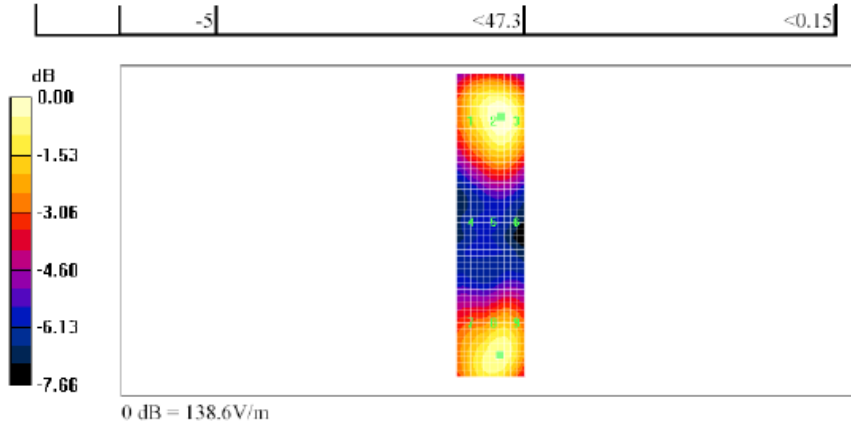
Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06


FCC ID
L6ARHA110LW

Date/Time: 14/07/2005 11:44:51 AM


Page 2 of 2



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	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 24 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

A.3 RF emission field plots

	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 25 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 7/15/2014 10:36:10 AM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_GSM 850

DUT: BlackBerry Smartphone; Type: Sample ; Serial: 2FFEB280

Communication System: UID 0, GSM 850; Frequency: 824.2 MHz, Frequency: 836.8 MHz,
Frequency: 848.8 MHz
Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³
Phantom section: RF Section
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field GSM850 measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_Low_Chan/Hearing Aid Compatibility

Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 68.82 V/m; Power Drift = -0.00 dB
Applied MIF = 3.44 dB
RF audio interference level = 38.42 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 36.98 dBV/m	Grid 2 M4 38.22 dBV/m	Grid 3 M4 38.19 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4

37.13 dBV/m	38.42 dBV/m	38.39 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
37.18 dBV/m	38.34 dBV/m	38.3 dBV/m

Category	Limits for E-Field Emissions < 960MHz	Limits for E-Field Emissions > 960MHz
M1	50 dBV/m - 55 dB V/m	40 dBV/m - 45 dB V/m
M2	45 dBV/m - 50 dB V/m	35 dBV/m - 40 dB V/m
M3	40 dBV/m - 45 dB V/m	30 dBV/m - 35 dB V/m
M4	<40 dBV/m	<30 dBV/m

Cursor:
Total = 38.42 dBV/m
E Category: M4
Location: -6.5, 2.5, 8.7 mm

Device E-Field GSM850 measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_Mid_Chan/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 74.98 V/m; Power Drift = 0.01 dB
Applied MIF = 3.44 dB
RF audio interference level = 39.60 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
37.22 dBV/m	39.18 dBV/m	39.18 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
37.65 dBV/m	39.6 dBV/m	39.59 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
38.16 dBV/m	39.72 dBV/m	39.65 dBV/m

Cursor:

Total = 39.72 dBV/m
E Category: M4
Location: -5.5, 25, 8.7 mm

Device E-Field GSM850 measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_High_Chan/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 72.33 V/m; Power Drift = 0.14 dB
Applied MIF = 3.44 dB
RF audio interference level = 39.10 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4 37.19 dBV/m	Grid 2 M4 38.88 dBV/m	Grid 3 M4 38.88 dBV/m
Grid 4 M4 37.37 dBV/m	Grid 5 M4 39.1 dBV/m	Grid 6 M4 39.09 dBV/m
Grid 7 M4 37.6 dBV/m	Grid 8 M4 39.05 dBV/m	Grid 9 M4 39.03 dBV/m

Cursor:
Total = 39.10 dBV/m
E Category: M4
Location: -8, 4.5, 8.7 mm

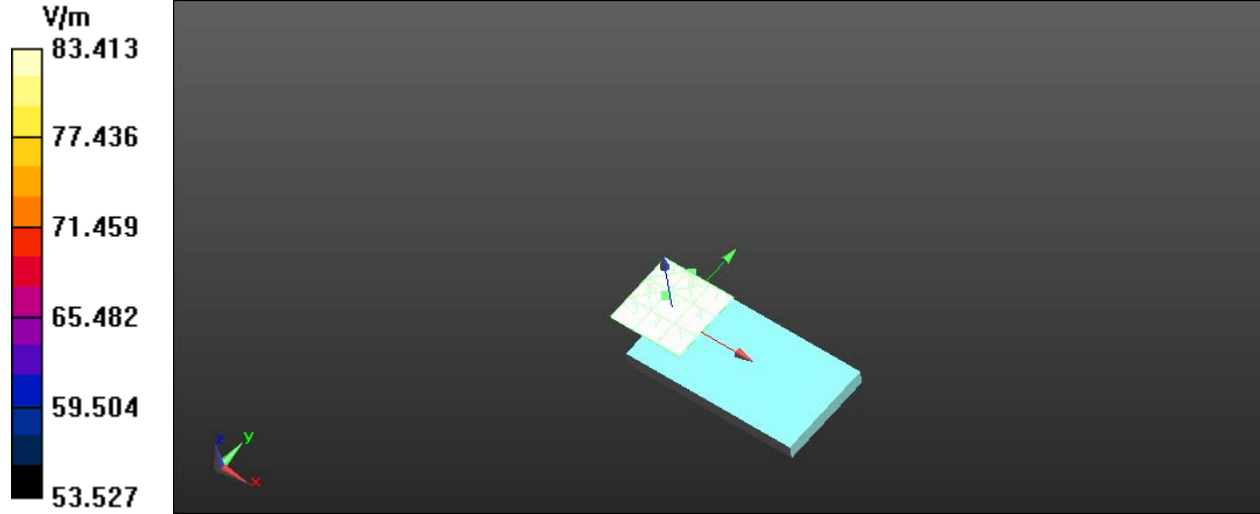



Author Data
Daoud Attayi

Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 29 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 7/15/2014 11:10:02 AM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_GSM 850_telecoil

DUT: BlackBerry Smartphone; Type: Sample ; Serial: 2FFEB280

Communication System: UID 0, GSM 850; Frequency: 848.8 MHz
Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³
Phantom section: RF Section
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field GSM850 measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_High_Chan_telecoil/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm
Reference Value = 73.36 V/m; Power Drift = 0.14 dB
Applied MIF = 3.46 dB
RF audio interference level = 39.29 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 38.07 dBV/m	Grid 2 M4 38.9 dBV/m	Grid 3 M4 38.51 dBV/m
Grid 4 M4 38.38 dBV/m	Grid 5 M4 39.29 dBV/m	Grid 6 M4 38.84 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4



Author Data
Daoud Attayi

Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW

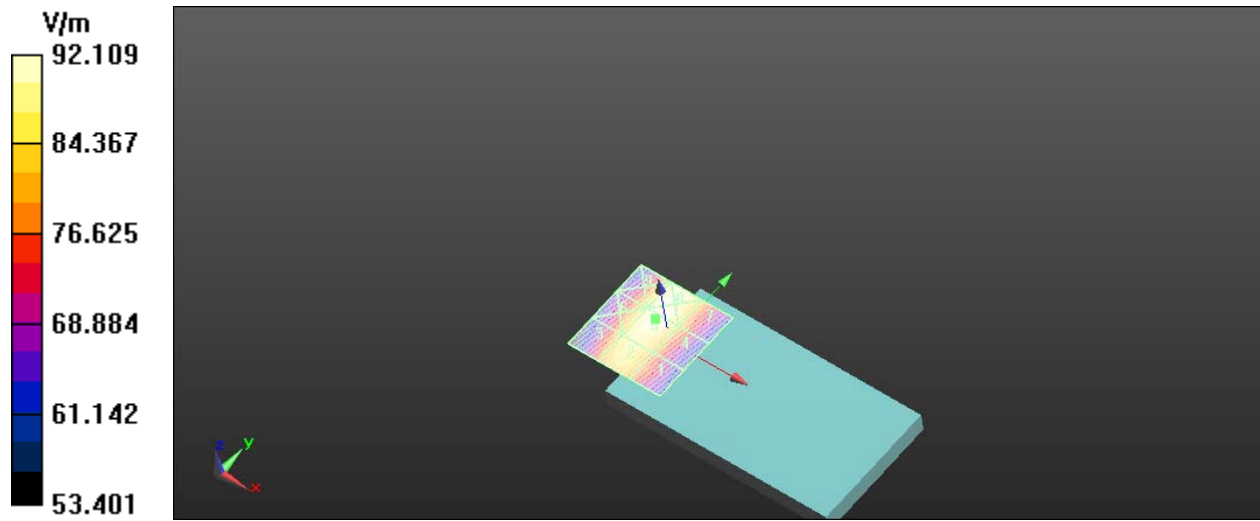
38.41 dBV/m | 39.26 dBV/m | 38.76 dBV/m


Cursor:

Total = 39.29 dBV/m

E Category: M4

Location: -7, 1, 8.7 mm



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 31 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 7/15/2014 11:21:41 AM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_GSM 1900

DUT: BlackBerry Smartphone; Type: Sample ; Serial: 2FFEB280

Communication System: UID 0, GSM 1900; Frequency: 1850.2 MHz, Frequency: 1880 MHz, Frequency: 1909.8 MHz

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), $z = 8.7$
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field GSM 1900 measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_Low_Chan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 7.433 V/m; Power Drift = 0.45 dB

Applied MIF = 3.44 dB

RF audio interference level = 28.65 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 28.6 dBV/m	Grid 2 M3 30.05 dBV/m	Grid 3 M4 29.86 dBV/m
Grid 4 M4 23.46 dBV/m	Grid 5 M4 25.31 dBV/m	Grid 6 M4 25.29 dBV/m
Grid 7 M4 26.72 dBV/m	Grid 8 M4 28.65 dBV/m	Grid 9 M4 28.64 dBV/m

Cursor:

Total = 30.05 dBV/m
 E Category: M3
 Location: -4, -25, 8.7 mm

**Device E-Field GSM 1900 measurement with ER probe/E Scan - ER3D - 2011:
 15 mm from Probe Center to the Device_Mid_Chan/Hearing Aid Compatibility**

Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
 Device Reference Point: 0, 0, -6.3 mm
 Reference Value = 6.388 V/m; Power Drift = 0.21 dB
 Applied MIF = 3.44 dB
 RF audio interference level = 29.12 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 28.58 dBV/m	Grid 2 M3 30.3 dBV/m	Grid 3 M3 30.27 dBV/m
Grid 4 M4 23.04 dBV/m	Grid 5 M4 25.37 dBV/m	Grid 6 M4 25.38 dBV/m
Grid 7 M4 27.01 dBV/m	Grid 8 M4 29.12 dBV/m	Grid 9 M4 29.09 dBV/m

Cursor:

Total = 30.30 dBV/m

E Category: M3

Location: -6.5, -25, 8.7 mm

**Device E-Field GSM 1900 measurement with ER probe/E Scan - ER3D - 2011:
15 mm from Probe Center to the Device_High_Chan/Hearing Aid Compatibility**

Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 7.075 V/m; Power Drift = -0.14 dB

Applied MIF = 3.44 dB

RF audio interference level = 27.56 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 27.14 dBV/m	Grid 2 M4 29.6 dBV/m	Grid 3 M4 29.6 dBV/m
Grid 4 M4 22.43 dBV/m	Grid 5 M4 25.39 dBV/m	Grid 6 M4 25.39 dBV/m
Grid 7 M4 25.54 dBV/m	Grid 8 M4 27.56 dBV/m	Grid 9 M4 27.53 dBV/m

Cursor:

Total = 29.60 dBV/m

E Category: M4

Location: -8, -25, 8.7 mm

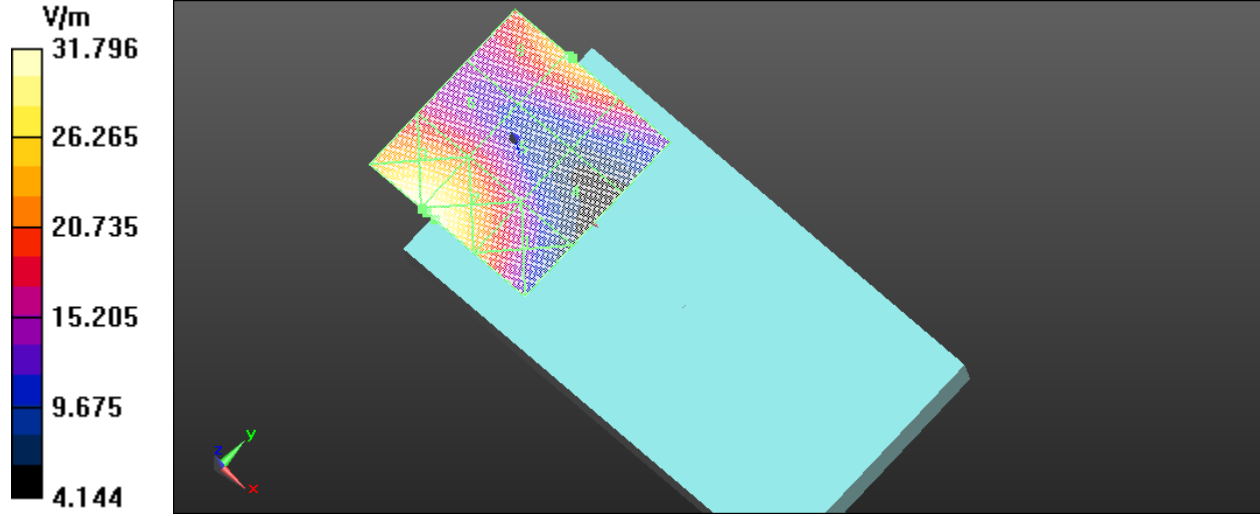


Author Data
Daoud Attayi

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March 18-24, July 14-15, 2014

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Date/Time: 7/15/2014 11:38:08 AM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_GSM 1900_telecoil

DUT: BlackBerry Smartphone; Type: Sample ; Serial: 2FFEB280

Communication System: UID 0, GSM 1900; Frequency: 1880 MHz
Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³
Phantom section: RF Section
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field GSM 1900 measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_Mid_Chan_telecoil/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm
Reference Value = 6.548 V/m; Power Drift = -0.01 dB
Applied MIF = 3.46 dB
RF audio interference level = 27.42 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 29.98 dBV/m	Grid 2 M3 30.81 dBV/m	Grid 3 M3 30.3 dBV/m
Grid 4 M4 26.2 dBV/m	Grid 5 M4 27.34 dBV/m	Grid 6 M4 27.08 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4



Author Data
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Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW

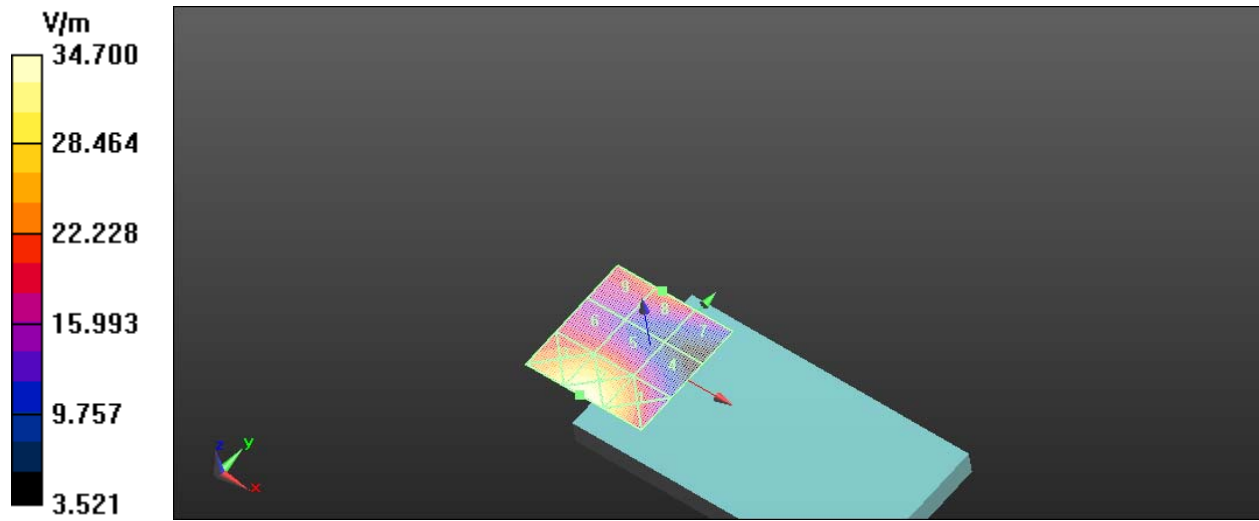
25.85 dBV/m | 27.42 dBV/m | 27.35 dBV/m


Cursor:

Total = 30.81 dBV/m

E Category: M3

Location: -6.5, -30, 8.7 mm



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 37 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 7/15/2014 12:13:33 PM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_UMTS band V

DUT: BlackBerry Smartphone; Type: Sample ; Serial: 2FFEB280

Communication System: UID 0, WCDMA FDD V; Frequency: 826.4 MHz, Frequency: 836.4 MHz, Frequency: 846.6 MHz
Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³
Phantom section: RF Section
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field UMTS band V measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_Low_Chan/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm
Reference Value = 76.54 V/m; Power Drift = 0.01 dB
Applied MIF = -25.91 dB
RF audio interference level = 10.15 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 8.56 dBV/m	Grid 2 M4 9.91 dBV/m	Grid 3 M4 9.9 dBV/m
Grid 4 M4 8.58 dBV/m	Grid 5 M4 10.15 dBV/m	Grid 6 M4 10.15 dBV/m

Grid 7 M4 8.71 dBV/m	Grid 8 M4 10.1 dBV/m	Grid 9 M4 10.09 dBV/m
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Cursor:
Total = 10.15 dBV/m
E Category: M4
Location: -8, 4, 8.7 mm

Device E-Field UMTS band V measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_Mid_Chan/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 67.69 V/m; Power Drift = -0.05 dB
Applied MIF = -25.91 dB
RF audio interference level = 9.18 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4 7.03 dBV/m	Grid 2 M4 8.78 dBV/m	Grid 3 M4 8.78 dBV/m
Grid 4 M4 7.47 dBV/m	Grid 5 M4 9.18 dBV/m	Grid 6 M4 9.18 dBV/m
Grid 7 M4 7.87 dBV/m	Grid 8 M4 9.31 dBV/m	Grid 9 M4 9.27 dBV/m

Cursor:
Total = 9.31 dBV/m
E Category: M4
Location: -5.5, 25, 8.7 mm

Device E-Field UMTS band V measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_High_Chan/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

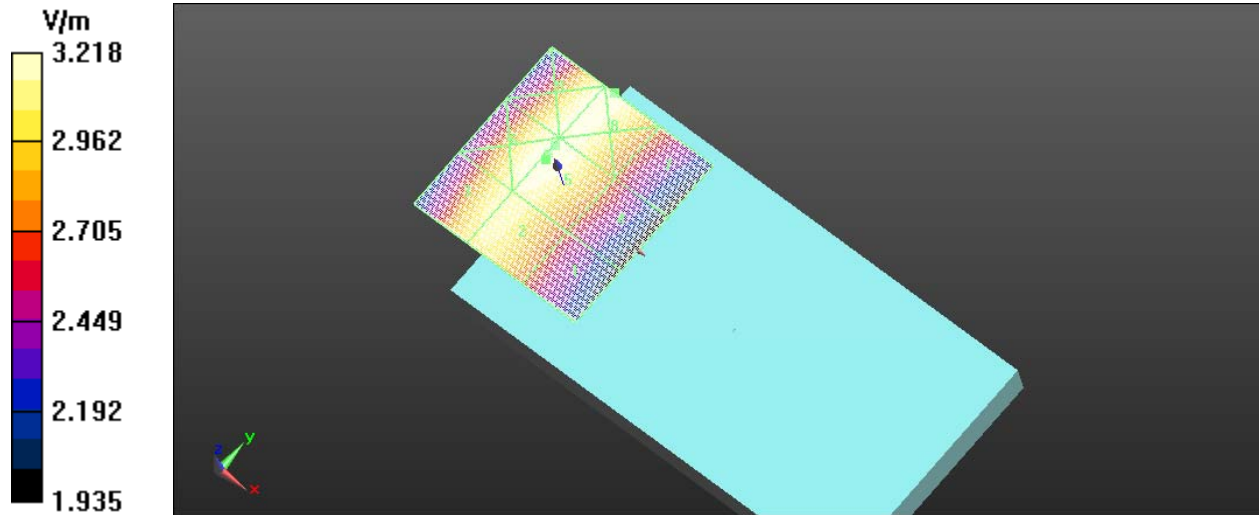
Device Reference Point: 0, 0, -6.3 mm
 Reference Value = 76.60 V/m; Power Drift = 0.04 dB
 Applied MIF = -25.91 dB
 RF audio interference level = 10.16 dBV/m
Emission category: M4


MIF scaled E-field

Grid 1 M4 8.6 dBV/m	Grid 2 M4 9.9 dBV/m	Grid 3 M4 9.89 dBV/m
Grid 4 M4 8.7 dBV/m	Grid 5 M4 10.16 dBV/m	Grid 6 M4 10.14 dBV/m
Grid 7 M4 8.81 dBV/m	Grid 8 M4 10.11 dBV/m	Grid 9 M4 10.1 dBV/m

Cursor:

Total = 10.16 dBV/m
 E Category: M4
 Location: -7.5, 2.5, 8.7 mm



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 40 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 7/15/2014 12:28:45 PM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_UMTS band V_telecoil

DUT: BlackBerry Smartphone; Type: Sample ; Serial: 2FFEB280

Communication System: UID 0, WCDMA FDD V (0); Frequency: 846.6 MHz
Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³
Phantom section: RF Section
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field UMTS band V measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_High_Chan_telecoil/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm
Reference Value = 77.07 V/m; Power Drift = -0.41 dB
Applied MIF = -25.91 dB
RF audio interference level = 10.21 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 9.22 dBV/m	Grid 2 M4 9.89 dBV/m	Grid 3 M4 9.37 dBV/m
Grid 4 M4 9.38 dBV/m	Grid 5 M4 10.21 dBV/m	Grid 6 M4 9.74 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4



Author Data
Daoud Attayi

Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW

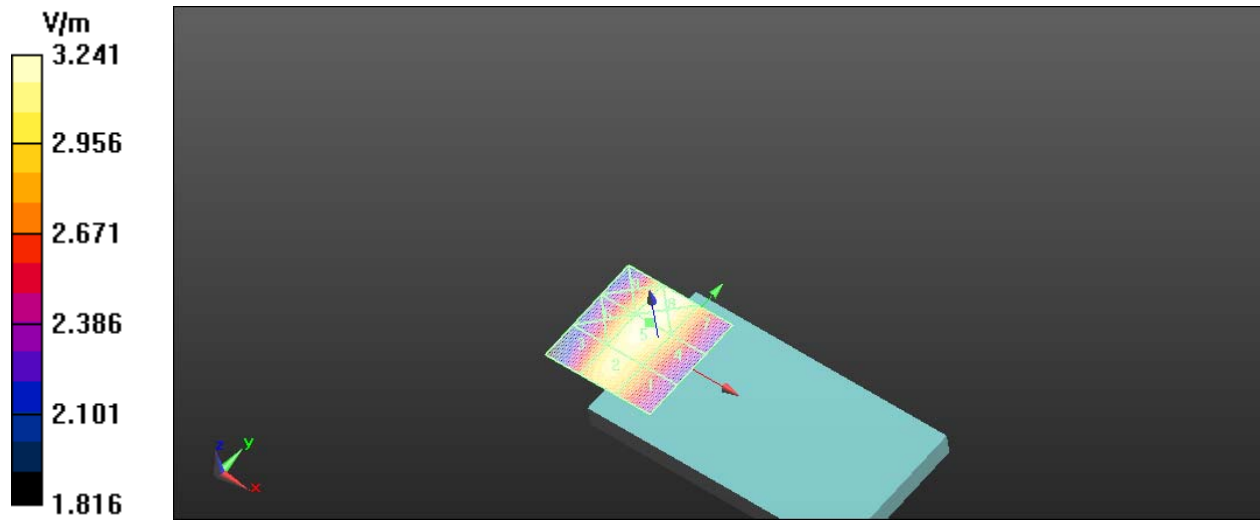
9.39 dBV/m | 10.21 dBV/m | 9.74 dBV/m


Cursor:

Total = 10.21 dBV/m

E Category: M4

Location: -7, 3.5, 8.7 mm



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 42 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 7/15/2014 12:39:49 PM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_UMTS band II

DUT: BlackBerry Smartphone; Type: Sample ; Serial: 2FFEB280

Communication System: UID 0, WCDMA FDD II; Frequency: 1852.4 MHz, Frequency: 1880 MHz, Frequency: 1907.6 MHz
Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³
Phantom section: RF Section
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field UMTS band II measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_Low_Chan/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm
Reference Value = 13.17 V/m; Power Drift = 0.01 dB
Applied MIF = -25.91 dB
RF audio interference level = 1.45 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 2.18 dBV/m	Grid 2 M4 4.45 dBV/m	Grid 3 M4 4.39 dBV/m
Grid 4 M4 -2.58 dBV/m	Grid 5 M4 0.37 dBV/m	Grid 6 M4 0.37 dBV/m

Grid 7 M4 0.05 dBV/m	Grid 8 M4 1.45 dBV/m	Grid 9 M4 1.33 dBV/m
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Cursor:
 Total = 4.45 dBV/m
 E Category: M4
 Location: -6.5, -25, 8.7 mm

Device E-Field UMTS band II measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_Mid_Chan/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
 Device Reference Point: 0, 0, -6.3 mm
 Reference Value = 13.21 V/m; Power Drift = -0.14 dB
 Applied MIF = -25.91 dB
 RF audio interference level = 1.26 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4 1.95 dBV/m	Grid 2 M4 4.4 dBV/m	Grid 3 M4 4.4 dBV/m
Grid 4 M4 -2.79 dBV/m	Grid 5 M4 0.36 dBV/m	Grid 6 M4 0.37 dBV/m
Grid 7 M4 -0.65 dBV/m	Grid 8 M4 1.26 dBV/m	Grid 9 M4 1.24 dBV/m

Cursor:
 Total = 4.40 dBV/m
 E Category: M4
 Location: -8, -25, 8.7 mm

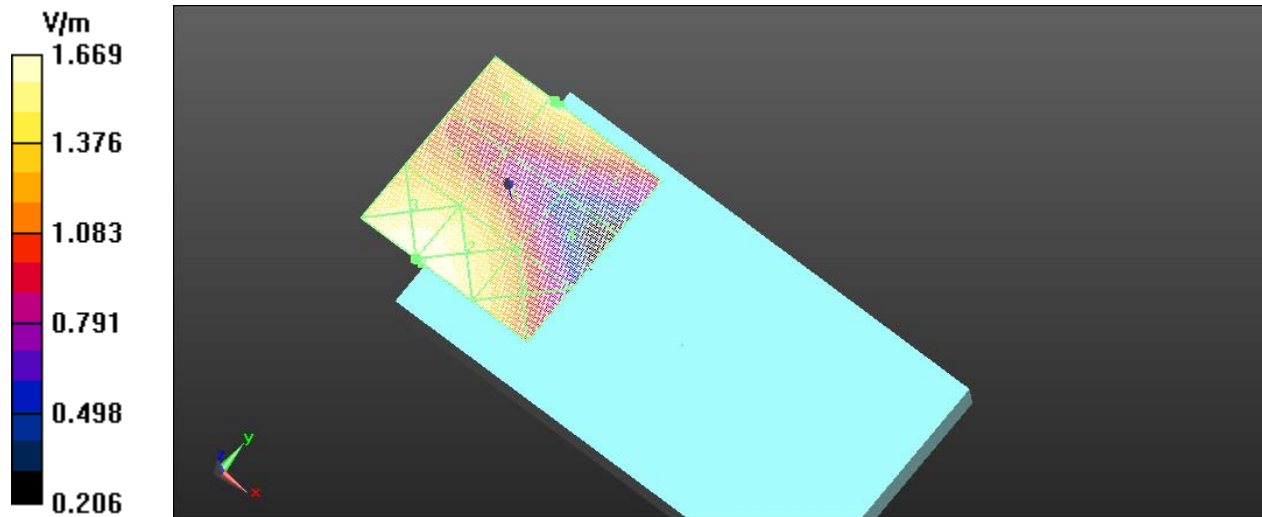
Device E-Field UMTS band II measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_High_Chan/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm


Device Reference Point: 0, 0, -6.3 mm
 Reference Value = 12.73 V/m; Power Drift = -0.09 dB
 Applied MIF = -25.91 dB
 RF audio interference level = 1.66 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4 2.23 dBV/m	Grid 2 M4 4.76 dBV/m	Grid 3 M4 4.76 dBV/m
Grid 4 M4 -2.71 dBV/m	Grid 5 M4 0.48 dBV/m	Grid 6 M4 0.47 dBV/m
Grid 7 M4 -0.83 dBV/m	Grid 8 M4 1.66 dBV/m	Grid 9 M4 1.63 dBV/m

Cursor:
 Total = 4.76 dBV/m
 E Category: M4
 Location: -8.5, -25, 8.7 mm



	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RHA111LW		Page 45 (46)
	Author Data Daoud Attayi	Dates of Test March 18-24, July 14-15, 2014	Report No RTS-6058-1407-06

Date/Time: 7/15/2014 12:51:32 PM

Test Laboratory: BlackBerry RTS

HAC RF_E-Field_UMTS band II_telecoil

DUT: BlackBerry Smartphone; Type: Sample ; Serial: 2FFEB280

Communication System: UID 0, WCDMA FDD II (0); Frequency: 1907.6 MHz
Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³
Phantom section: RF Section
Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2011)

DASY Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE3 Sn472; Calibrated: 3/18/2014
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA
- DASYS 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field UMTS band II measurement with ER probe/E Scan - ER3D - 2011: 15 mm from Probe Center to the Device_High_Chan_telecoil/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm
Reference Value = 12.97 V/m; Power Drift = -0.41 dB
Applied MIF = -25.91 dB
RF audio interference level = 2.23 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 3.97 dBV/m	Grid 2 M4 5.08 dBV/m	Grid 3 M4 4.71 dBV/m
Grid 4 M4 0.63 dBV/m	Grid 5 M4 2.23 dBV/m	Grid 6 M4 2.02 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4



Author Data
Daoud Attayi

Dates of Test
March 18-24, July 14-15, 2014

Report No
RTS-6058-1407-06

FCC ID
L6ARHA110LW

-1.89 dBV/m | -0.25 dBV/m | -0.33 dBV/m

Cursor:

Total = 5.08 dBV/m

E Category: M4

Location: -8, -30, 8.7 mm

